TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74AC74P,TC74AC74F,TC74AC74FN,TC74AC74FT

Dual D-Type Flip Flop with Preset and Clear

The TC74AC74 is an advanced high speed CMOS D-FLIP FLOP fabricated with silicon gate and double-layer metal wiring C²MOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

The signal level applied to the D INPUT is transferred to Q OUTPUT during the positive going transition of the CK pulse.

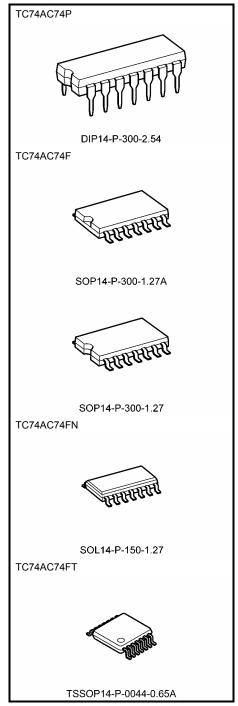
CLR and PR are independent of the CK and are accomplished by setting the appropriate input to an "L" level.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

Features

- High speed: $f_{max} = 200 \text{ MHz}$ (typ.) at $V_{CC} = 5 \text{ V}$
- Low power dissipation: $ICC = 4 \mu A \text{ (max)}$ at $Ta = 25^{\circ}C$
- High noise immunity: VNIH = VNIL = 28% VCC (min)
- Symmetrical output impedance: $|I_{OH}| = I_{OL} = 24$ mA (min) Capability of driving 50 Ω transmission lines.
- Balanced propagation delays: $t_pLH \simeq t_pHL$
- Wide operating voltage range: VCC (opr) = 2 V to 5.5 V
- Pin and function compatible with 74F74

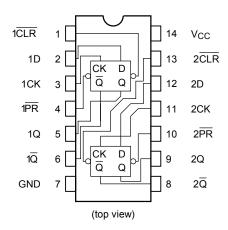
Note: xxxFN (JEDEC SOP) is not available in Japan.



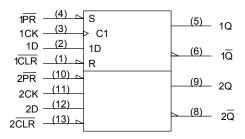
Weight

DIP14-P-300-2.54 : 0.96 g (typ.) SOP14-P-300-1.27A : 0.18 g (typ.) SOP14-P-300-1.27 : 0.18 g (typ.) SOL14-P-150-1.27 : 0.12 g (typ.) TSSOP14-P-0044-0.65A : 0.06 g (typ.)

Pin Assignment



IEC Logic Symbol

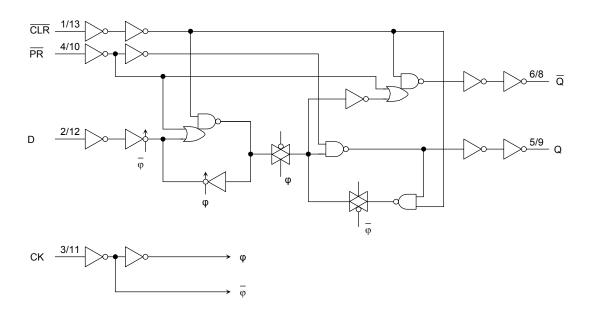


Truth Table

	Inp	uts		Outputs		Function
CLR	PR	D	CK	Q	Q	Function
L	Н	Х	Х	L	Н	Clear
Н	L	Х	Х	Н	L	Preset
L	L	Х	Х	Н	Н	ı
Н	Н	L		L	Н	_
Н	Н	Н		Н	L	ı
Н	Н	Х	\Box	Qn	$\overline{\overline{Q}}_n$	No Change

X: Don't care

System Diagram





Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V _{CC}	−0.5 to 7.0	V
DC input voltage	V _{IN}	-0.5 to V _{CC} + 0.5	V
DC output voltage	V _{OUT}	-0.5 to V _{CC} + 0.5	V
Input diode current	I _{IK}	±20	mA
Output diode current	lok	±50	mA
DC output current	I _{OUT}	±50	mA
DC V _{CC} /ground current	Icc	±100	mA
Power dissipation	P _D	500 (DIP) (Note 2)/180 (SOP/TSSOP)	mW
Storage temperature	T _{stg}	-65 to 150	°C

Note1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Note2: 500 mW in the range of Ta = -40° C to 65°C. From Ta = 65°C to 85°C a derating factor of $-10 \text{ mW}/^{\circ}$ C should be applied up to 300 mW.

Recommended Operating Conditions (Note)

Characteristics	Symbol	Rating	Unit	
Supply voltage	V _{CC}	2.0 to 5.5	V	
Input voltage	V _{IN}	0 to V _{CC}	V	
Output voltage	V _{OUT}	0 to V _{CC}	V	
Operating temperature	T _{opr}	-40 to 85	°C	
Input rise and fall time	dt/dV	0 to 100 (V _{CC} = 3.3 ± 0.3 V)	ns/V	
input rise and rail time	u/u v	0 to 20 (V _{CC} = 5 ± 0.5 V)		

Note: The recommended operating conditions are required to ensure the normal operation of the device.

Unused inputs must be tied to either VCC or GND.



Electrical Characteristics

DC Characteristics

Characteristics	Symbol	Test Condition			-	Га = 25°(Ta = -40 to 85°C		Unit		
Ondracteristics	Cymbol				V _{CC} (V)	Min	Тур.	Max	Min	Max	Ome	
			_		2.0	1.50	_	_	1.50	_	V	
High-level input voltage	V_{IH}				3.0	2.10	_	_	2.10	_		
				5.5	3.85	_	_	3.85	_			
					2.0	_	_	0.50	_	0.50		
Low-level input voltage	V _{IL}	_		3.0	_	_	0.90	_	0.90	V		
					5.5		_	1.65	_	1.65		
	V _{OH}					1.9	2.0	_	1.9	_		
		V _{IN} = V _{IH} or V _{IL}	I _{OH} = -50 μA		3.0	2.9	3.0	_	2.9	_	V	
High-level output					4.5	4.4	4.5		4.4	_		
voltage			I _{OH} = -4 mA		3.0	2.58	_	_	2.48	_	ľ	
			I _{OH} = -24 mA		4.5	3.94	_	_	3.80	_		
			I _{OH} = -75 mA	(Note)	5.5	l	_		3.85	_		
	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 50 μA		2.0	_	0.0	0.1	_	0.1		
					3.0	_	0.0	0.1	_	0.1		
Low-level output					4.5		0.0	0.1	_	0.1	V	
voltage			I _{OL} = 12 mA		3.0	_	_	0.36	_	0.44	·	
			I _{OL} = 24 mA		4.5	_	_	0.36	_	0.44		
			I _{OL} = 75 mA	(Note)	5.5	1	_	-	_	1.65		
Input leakage current	I _{IN}	V _{IN} = V _{CC} or GND		5.5	ı	_	±0.1	_	±1.0	μΑ		
Quiescent supply current	I _{CC}	V _{IN} = V _{CC} or GND		5.5	_	_	4.0	_	40.0	μΑ		

Note: This spec indicates the capability of driving 50 Ω transmission lines.

One output should be tested at a time for a 10 ms maximum duration.

Timing Requirements (input: tr = tf = 3 ns)

Characteristics	Symbol	Test Condition	Ta = 25°C	Ta = -40 to 85°C	Unit		
			V _{CC} (V)	Limit	Limit		
Minimum pulse width	t _{w (L)}		3.3 ± 0.3	7.0	7.0	20	
(CK)	t _{w (H)}	_	5.0 ± 0.5	5.0	5.0	ns	
Minimum pulse width	4		3.3 ± 0.3	7.0	7.0	no	
($\overline{\text{CLR}}$, $\overline{\text{PR}}$)	t _{w (L)}	_	5.0 ± 0.5	5.0	5.0	ns	
Minimum set-up time	4		3.3 ± 0.3	6.0	6.0		
willimum set-up time	t _s	_	5.0 ± 0.5	3.5	3.5	ns	
Minimum hald time			3.3 ± 0.3	1.0	1.0		
Minimum hold time	t _h	_	5.0 ± 0.5	1.0	1.0	ns	
Minimum removal time			3.3 ± 0.3	4.0	4.0		
(CLR , PR)	t _{rem}	_	5.0 ± 0.5	2.0	2.0	ns	

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AC Characteristics (C_L = 50 pF, R_L = 500 Ω , input: t_r = t_f = 3 ns)

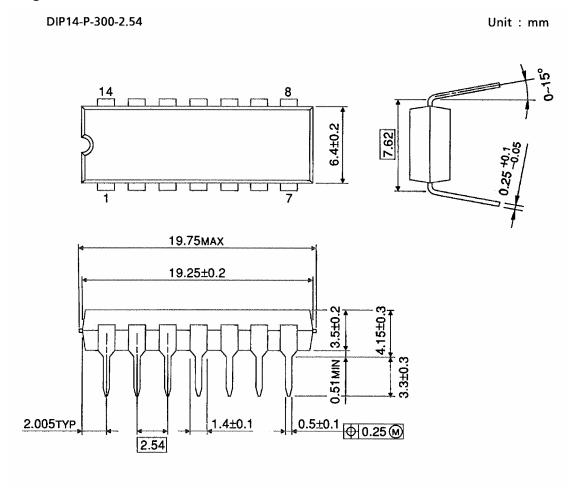
Characteristics	Symbol	Test Condition		Ta = 25°C			Ta = -40 to 85°C		Unit	
	,		V _{CC} (V)	Min	Тур.	Max	Min	Max		
Propagation delay time $ (\text{CK-Q}, \ \overline{\textbf{Q}}\) $	t _{pLH} t _{pHL}	_	3.3 ± 0.3 5.0 ± 0.5	_ _	8.2 6.1	13.9 8.7	1.0 1.0	16.0 10.0	ns	
Propagation delay time (CLR , PR -Q, Q)	t _{pLH}	_	3.3 ± 0.3 5.0 ± 0.5	_ _	8.0 5.7	13.1 8.2	1.0 1.0	15.0 9.4	ns	
Maximum clock frequency	f _{max}	_	3.3 ± 0.3 5.0 ± 0.5	60 100	120 160	<u>-</u>	60 100	_ _	MHz	
Input capacitance	C _{IN}	_		_	5	10	_	10	pF	
Power dissipation capacitance	C _{PD}		(Note)	ı	77	_	_	_	pF	

Note: CPD is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

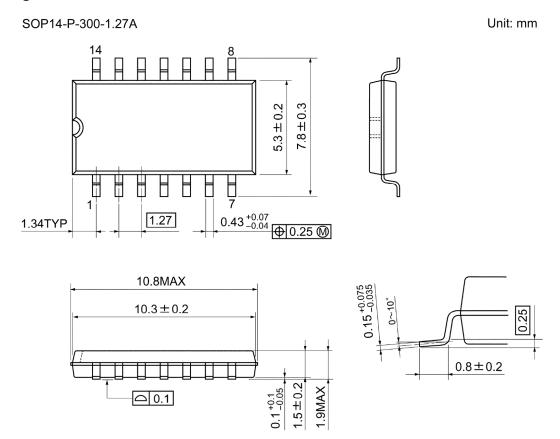
Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/2 (per F/F)$





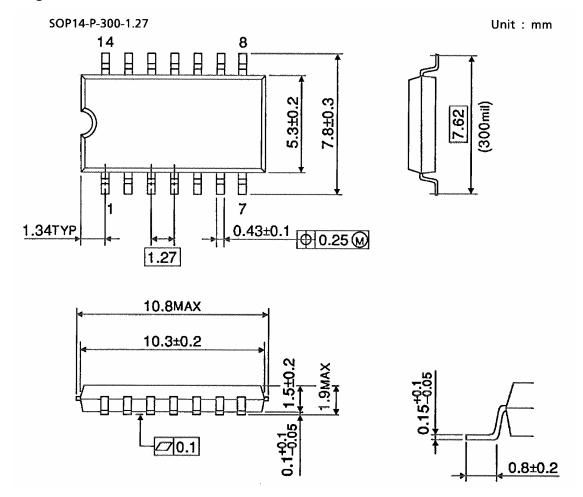
Weight: 0.96 g (typ.)



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Weight: 0.18 g (typ.)



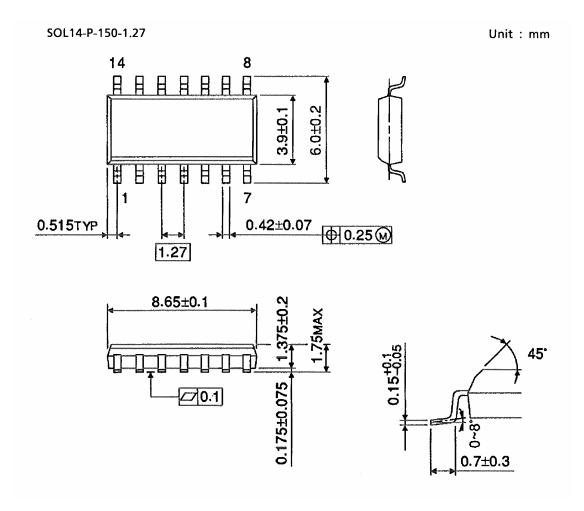


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Weight: 0.18 g (typ.)



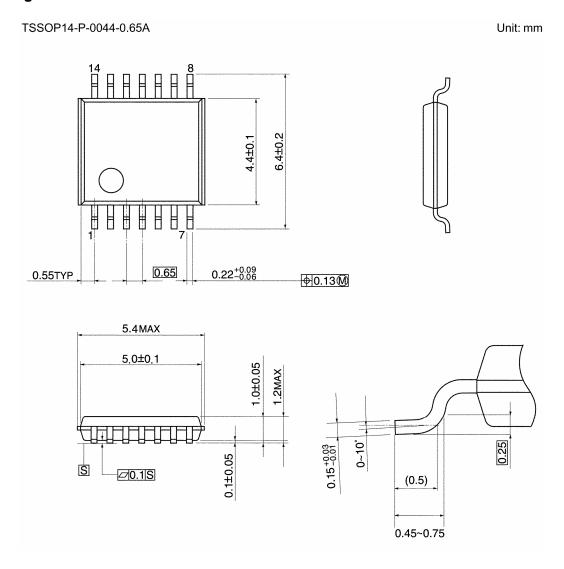
Package Dimensions (Note)



Note: This package is not available in Japan.

Weight: 0.12 g (typ.)





Weight: 0.06 g (typ.)

Note: Lead (Pb)-Free Packages

DIP14-P-300-2.54 SOP14-P-300-1.27A SOL14-P-150-1.27 TSSOP14-P-0044-0.65A

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